

2SK2122

Silicon N-Channel Power F-MOS

■ Features

- Avalanche energy capability guaranteed : EAS > 3.2mJ
- High-speed switching : $t_f = 50\text{ns}$
- No secondary breakdown

■ Applications

- Non-contact relay
- Solenoid drive
- Motor drive
- Control equipment
- Switching mode regulator

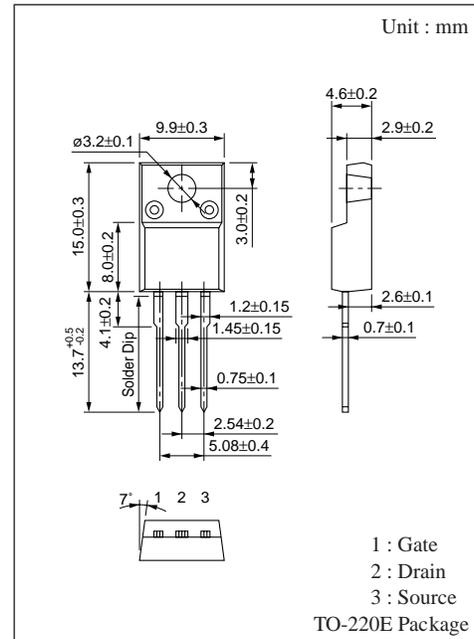
■ Absolute Maximum Ratings ($T_c = 25^\circ\text{C}$)

Parameter	Symbol	Rating	Unit	
Drain-Source breakdown voltage	V_{DSS}	250	V	
Gate-Source voltage	V_{GSS}	± 20	V	
Drain current	DC	I_D	± 8	A
	Pulse	I_{DP}	± 16	A
Avalanche energy capability	EAS*	3.2	mJ	
Allowable power dissipation	$T_C=25^\circ\text{C}$	P_D	40	W
	$T_a=25^\circ\text{C}$		2	
Channel temperature	T_{ch}	150	$^\circ\text{C}$	
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$	

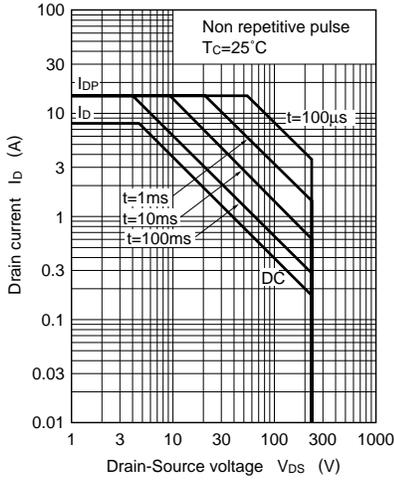
* $L = 0.1\text{mH}$, $I_L = 8\text{A}$, $V_{DD} = 50\text{V}$, 1 pulse

■ Electrical Characteristics ($T_c = 25^\circ\text{C}$)

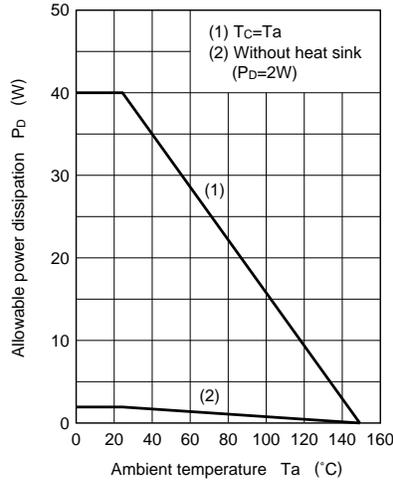
Parameter	Symbol	Condition	Min	Typ	Max	Unit	
Drain-Source cut-off current	I_{DSS}	$V_{DS} = 200\text{V}$, $V_{GS} = 0$			0.1	mA	
Gate-Source leakage current	I_{GSS}	$V_{GS} = \pm 20\text{V}$, $V_{DS} = 0$			± 1	μA	
Drain-Source breakdown voltage	V_{DSS}	$I_D = 1\text{mA}$, $V_{GS} = 0$	250			V	
Gate threshold voltage	V_{th}	$V_{DS} = 10\text{V}$, $I_D = 1\text{mA}$	2		5	V	
Drain-Source ON-resistance	$R_{DS(on)}$	$V_{GS} = 10\text{V}$, $I_D = 5\text{A}$		0.4	0.6	Ω	
Forward transadmittance	$ Y_{fs} $	$V_{DS} = 10\text{V}$, $I_D = 5\text{A}$	2.7	4.7		S	
Diode forward voltage	V_{DSF}	$I_{DR} = 8\text{A}$, $V_{GS} = 0$			-1.7	V	
Input capacitance	C_{iss}	$V_{DS} = 10\text{V}$, $V_{GS} = 0$, $f = 1\text{MHz}$		1100		pF	
Output capacitance	C_{oss}				200		pF
Feedback capacitance	C_{rss}				60		pF
Turn-on time (delay time)	$t_{d(on)}$	$V_{GS} = 10\text{V}$, $I_D = 5\text{A}$ $V_{DD} = 100\text{V}$, $R_L = 20\Omega$		20		ns	
Rise time	t_r				20		ns
Fall time	t_f				30		ns
Turn-off time (delay time)	$t_{d(off)}$				130		ns
Channel-Case heat resistance	$R_{th(ch-c)}$				3.125	$^\circ\text{C/W}$	



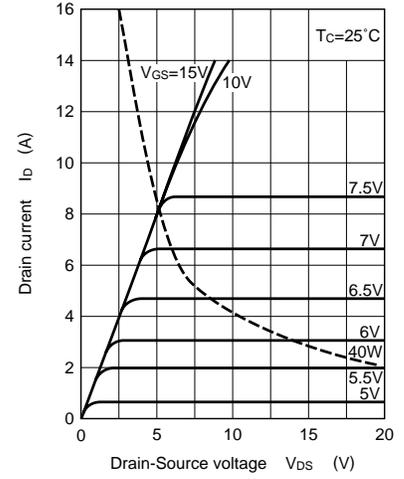
Area of safe operation (ASO)



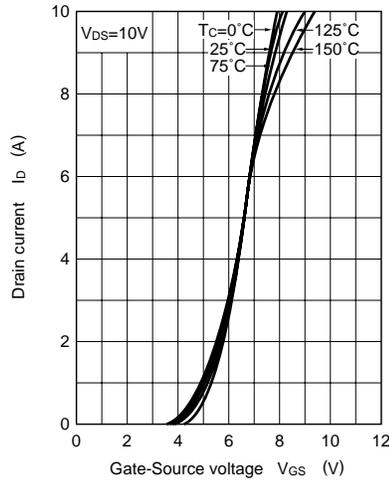
$P_D - T_a$



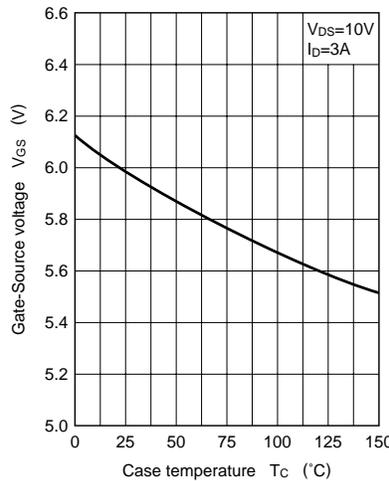
$I_D - V_{DS}$



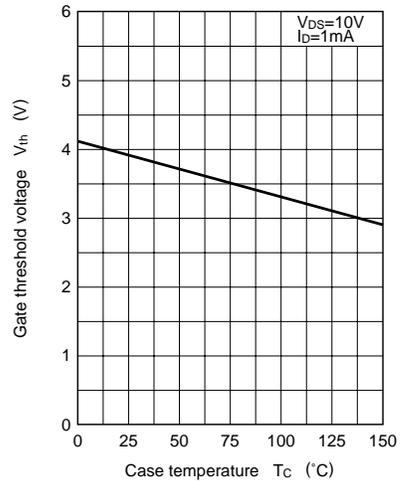
$I_D - V_{DS}$



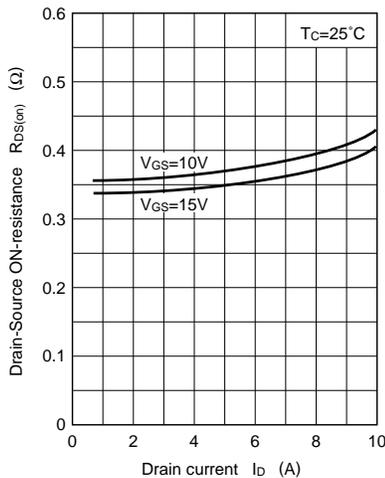
$V_{GS} - T_C$



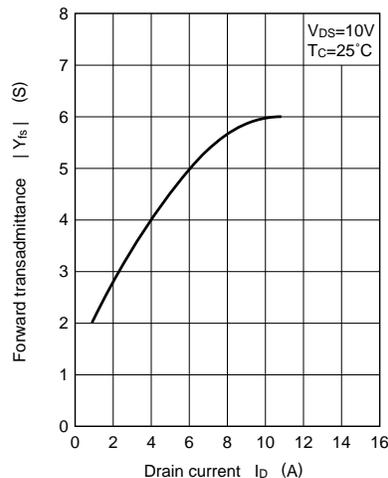
$V_{th} - T_C$



$R_{DS(on)} - I_D$



$|Y_{fs}| - I_D$



$C_{iss}, C_{oss}, C_{rss} - V_{DS}$

